

CD54HC354, CD74HC354, **CD74HCT354**

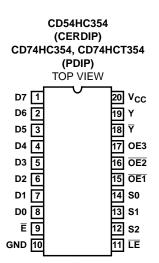
8-Line to 1-Line Data Selector/Multiplexer/Register With 3-State Outputs

SCHS277D - November 1997 - Revised May 2003

Features

- HC/HCT354
 - Transparent Data and Select Latches
- Buffered Inputs
- Three-State Complementary Outputs
- Bus Line Driving Capability
- Typical Propagation Delay: V_{CC} = 5V, C_L = 15pF, $T_{A} = 25^{\circ}C$
 - Data to Output = 18ns
- Fanout (Over Temperature Range)
 - Standard Outputs 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: NIL = 30%, NIH = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, $V_{IL} = 0.8V$ (Max), $V_{IH} = 2V$ (Min)
 - CMOS Input Compatibility, $I_I \leq 1\mu A$ at V_{OI} , V_{OH}

Pinout



Description

The CD54HC354, CD74HC354, and CD74HCT354 are data selectors/multiplexers that select one of eight sources. In both types, the data select bits S0, S1 and S2 are stored in transparent latches that are enabled by a low latch enable input, LE.

In the HC/HCT354 the data enable input, \overline{E} , controls transparent latches that pass data to the outputs when \overline{E} is high and latches in new data when \overline{E} is low.

In both types the three-state outputs are controlled by three output-enable inputs OE1, OE2, and OE3.

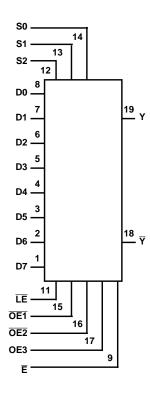
Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD54HC354F3A	-55 TO 125	20 Ld CERDIP
CD74HC354E	-55 to 125	20 Ld PDIP
CD74HCT354E	-55 to 125	20 Ld PDIP

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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Functional Diagram



TRUTH TABLE

			INPUTS					
s	ELECT (NOTE	1)	ENABLE DATA	ou	TPUT ENABI	OUTI	PUTS	
S2	S1	S0	Ē	OE1	OE2	OE3	Ŧ	Y
Х	Х	Х	Х	Н	Х	Х	Z	Z
х	Х	Х	Х	Х	Н	Х	Z	Z
х	Х	х	х	Х	Х	L	Z	Z
L	L	L	L	L	L	Н	DO	D0
L	L	L	Н	L	L	Н	D0 _n	D0 _n
L	L	н	L	L	L	Н	D1	D1
L	L	н	Н	L	L	Н	D1 _n	D1 _n
L	н	L	L	L	L	Н	D2	D2
L	н	L	Н	L	L	Н	D2 _n	D2 _n
L	н	н	L	L	L	Н	D3	D3
L	н	н	Н	L	L	Н	D3 _n	D3 _n
н	L	L	L	L	L	Н	D4	D4
н	L	L	Н	L	L	Н	D4 _n	D4 _n
н	L	н	L	L	L	н	D5	D5
Н	L	н	Н	L	L	н	D5 _n	D5 _n
Н	н	L	L	L	L	н	D6	D6
н	н	L	Н	L	L	н	D6 _n	D6 _n

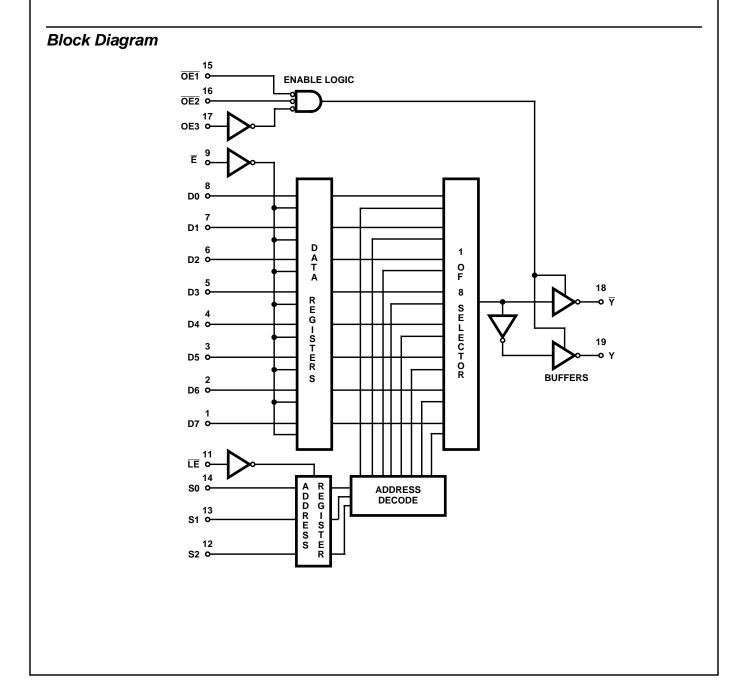
CD54HC354, CD74HC354, CD74HCT354

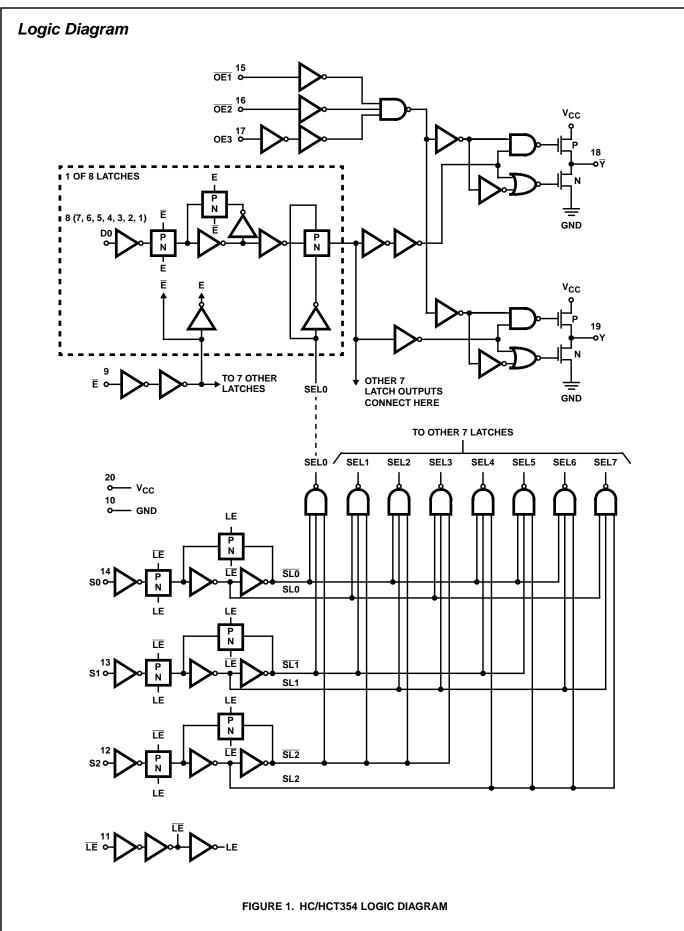
				•	,			
			INPUTS					
SE	LECT (NOTE	1)	ENABLE DATA	OUTPUT ENABLES			ουτι	PUTS
S2	S1	S0	Ē	OE1 OE2 OE3			Ŧ	Y
Н	Н	Н	L	L	L	Н	D7	D7
н	н	Н	Н	L	L	Н	D7 _n	D7 _n

H = High Voltage Level (Steady State); L = Low Voltage Level (Steady State); X = Don't Care; Z = High Impedance State (Off State); $D0_n...D7_n$ = the level of steady-state inputs D0 through D7, respectively, before the most recent low-to-high transition of data control.

NOTE:

1. This column shows the input address setup with $\overline{\text{LE}}$ low.





Absolute Maximum Ratings

DC Supply Voltage, V _{CC} 0.5V to 7V DC Input Diode Current, I _{IK}
For V _I < -0.5V or V _I > V _{CC} + 0.5V±20mA
DC Output Diode Current, I_{OK} For V _O < -0.5V or V _O > V _{CC} + 0.5V
DC Drain Current, per Output, I _O For -0.5V < V _O < V _{CC} + 0.5V±35mA
DC Output Source or Sink Current per Output Pin, I_O For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$
$DC V_{CC} \text{ or Ground Current, } I_{CC} \dots \pm 50 \text{mA}$

Operating Conditions

Temperature Range, T_A
Supply Voltage Range, V _{CC}
HC Types
HCT Types
DC Input or Output Voltage, VI, VO 0V to VCC
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

Thermal Resistance (Typical, Note 2)	θ_{JA} (^o C/W)
E (PDIP) Package	. 69
Maximum Junction Temperature	150 ⁰ C
Maximum Storage Temperature Range	65 ⁰ C to 150 ⁰ C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TEST CONDITIONS		25 ⁰ C			-40°C TO 85°C		-55°C TO 125°C			
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES			-						_			-
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads		VIL	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
emee Louds			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	7		-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Voltage TTL Loads (Bus Driver)			-7.8	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads		VIL	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
emed Loads			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Voltage TTL Loads (Bus Driver)			7.8	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	Ιį	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA

CD54HC354, CD74HC354, CD74HCT354

			ST ITIONS		25 ⁰ C			-40°C 1	ГО 85 ⁰ С	-55°C T	O 125 ⁰ C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μA
Three-State Leakage Current	I _{OZ}	V _{IL} or V _{IH}	V _O = V _{CC} or GND	6	-	-	±0.5	-	±5.0	-	±10	μΑ
HCT TYPES									•	•	•	
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	VIL	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} to GND	-	5.5	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I _{CC} (Note 3)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA
Three-State Leakage Current	loz	V _{IL} or V _{IH}	V _O = V _{CC} or GND	5.5	-	-	±0.5	-	±5.0	-	±10	μΑ

NOTE:

3. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
D0-D7	0.50
S0, S1, S3	0.70
OE1, OE2	0.80
OE3	0.25
LE	0.25
Ē	0.60

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360µA max at $25^{0}C.$

Prerequisite For Switching Specifications

		TEST	V _{CC}		25 ⁰ C		-40 ⁰ C T	O 85°C	-55 ⁰ C T	O 125 ⁰ C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
E Pulse Width	t _{PLH} , t _{PHL}	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
LE Pulse Width	t _{PLH} , t _{PHL}	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
Set-up Times $\text{Dn}\to\overline{\text{E}}$	ts∪	-	2	50	-	-	65	-	75	-	ns
			4.5	10	-	-	13	-	15	-	ns
			6	9	-	-	11	-	13	-	ns
Set-up Times Sn $\rightarrow \overline{\text{LE}}$	t _{SU}	-	2	50	-	-	65	-	75	-	ns
			4.5	10	-	-	13	-	15	-	ns
			6	9	-	-	11	-	13	-	ns
Hold Times $\text{Dn}\to\overline{\text{E}}$	t _H	-	2	45	-	-	55	-	70	-	ns
			4.5	9	-	-	11	-	14	-	ns
			6	8	-	-	9	-	12	-	ns
Hold Times Sn $\rightarrow \overline{\text{LE}}$	t _H	-	2	45	-	-	55	-	70	-	ns
			4.5	9	-	-	11	-	14	-	ns
			6	8	-	-	9	-	12	-	ns
HCT TYPES	•	•									
E Pulse Width	t _{PLH} , t _{PHL}	-	4.5	16	-	-	20	-	24	-	ns
LE Pulse Width	t _{PLH} , t _{PHL}	-	4.5	16	-	-	20	-	24	-	ns
Set-up Times $Dn\to\overline{E}$	t _{SU}	-	4.5	10	-	-	13	-	15	-	ns
Set-up Times Sn $\rightarrow \overline{\text{LE}}$	t _{SU}	-	4.5	10	-	-	13	-	15	-	ns
Hold Times $\text{Dn}\to\overline{\text{E}}$	t _H	-	4.5	9	-	-	11	-	14	-	ns
Hold Times Sn $\rightarrow \overline{\text{LE}}$	t _H	-	4.5	9	-	-	11	-	14	-	ns

Switching Specifications Input t_r , $t_f = 6ns$

		TEST 25°C		°C	-40°C TO 85°C	-55 ⁰ C TO 125 ⁰ C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES					-			-
Propagation Delay, $Dn \rightarrow Y, \overline{Y}$	t _{PLH} , t _{PHL}	$C_L = 50 pF$	2	-	210	265	315	ns
			4.5	-	42	53	63	ns
			6	-	36	45	54	ns
		C _L = 15pF	5	18	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	250	315	375	ns
$\overline{E} \rightarrow Y, \overline{Y}$			4.5	-	50	63	75	ns
			6	-	43	54	64	ns
		C _L = 15pF	5	21	-	-	-	ns

PARAMETER	SYMBOL	TEST CONDITIONS	V _{CC} (V)	25 ⁰ C		-40°C TO 85°C	-55°C TO 125 ⁰ C	
				ТҮР	МАХ	MAX	MAX	
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	260	325	390	ns
$Sn \rightarrow Y, \overline{Y}$			4.5	-	52	65	78	ns
			6	-	44	55	66	ns
		C _L = 15pF	5	22	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	290	365	435	ns
$\overline{\text{LE}} \rightarrow Y, \overline{Y}$			4.5	-	58	73	87	ns
			6	-	49	62	74	ns
		C _L = 15pF	5	24	-	-	-	ns
Output Disabling Time,	t _{PLZ} , t _{PHZ}	C _L = 50pF	2	-	155	195	235	ns
\overline{OE} n to Y, \overline{Y}			4.5	-	31	39	47	ns
			6	-	26	33	40	ns
		C _L = 15pF	5	13	-	-	-	ns
Output Disabling Time, OE3 to Y, Ÿ	t _{PLZ} , t _{PHZ}	C _L = 50pF	2	-	155	195	235	ns
			4.5	-	31	39	47	ns
			6	-	26	33	40	ns
		C _L = 15pF	5	13	-	-	-	ns
Output Enabling Time, OEn to Y, Y	t _{PZL} , t _{PZH}	C _L = 50pF	2	-	150	190	225	ns
			4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		C _L = 15pF	5	12, 13	-	-	-	ns
Output Enabling Time, OE3 to Y, \overline{Y}	t _{PZL} , t _{PZH}	C _L = 50pF	2	-	160	200	240	ns
			4.5	-	32	40	48	ns
			6	-	27	34	41	ns
		C _L = 15pF	5	12, 13	-	-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	60	75	90	ns
			4.5	-	12	15	18	ns
			6	-	10	13	15	ns
Input Capacitance	Cl	-	-	-	10	10	10	pF
Three-State Capacitance	Co	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	90	-	-	-	pF
HCT TYPES		·				· · · · · ·		
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	47	59	71	ns
$Dn \rightarrow Y, \overline{Y}$		C _L = 15pF	5	20	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	54	68	81	ns
$\overline{E} \to Y, \overline{Y}$		C _L = 15pF	5	23	-	-	-	ns

		TEST	V _{CC} (V)	25 ⁰ C		-40°C TO 85°C	-55 ⁰ C TO 125 ⁰ C	
PARAMETER	SYMBOL	CONDITIONS		ТҮР	МАХ	MAX	MAX	
Propagation Delay, Sn \rightarrow Y, \overline{Y}	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	59	74	89	ns
		C _L = 15pF	5	25	-	-	-	ns
Propagation Delay, $\overline{\text{LE}} \rightarrow \text{Y}, \overline{\text{Y}}$	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	63	79	94	ns
		C _L = 15pF	5	25	-	-	-	ns
Output Disabling Time, \overline{OEn} to Y, \overline{Y}	t _{PLZ} , t _{PHZ}	C _L = 50pF	4.5	-	33	41	50	ns
		C _L = 15pF	5	13, 16	-	-	-	ns
Output Disabling Time, OE3 to Y, \overline{Y}	t _{PLZ} , t _{PHZ}	C _L = 50pF	4.5	-	39	49	59	ns
		C _L = 15pF	5	13, 16	-	-	-	ns
Output Enabling Time, $\overline{OE}n$ to Y, \overline{Y}	t _{PZL} , t _{PZH}	C _L = 50pF	4.5	-	34	43	51	ns
		C _L = 15pF	5	14	-	-	-	ns
Output Enabling Time, OE3 to Y, \overline{Y}	t _{PZL} , t _{PZH}	C _L = 50pF	4.5	-	34	43	51	ns
		C _L = 15pF	5	14	-	-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	12	15	18	ns
Input Capacitance	C _{IN}	-	-	-	10	10	10	pF
Three-State Capacitance	CO	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	92	-	-	-	pF

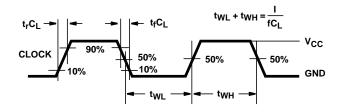
Switching Specifications Input tr, tf = 6ns (Continued)

NOTES:

4. C_{PD} is used to determine the dynamic power consumption, per device.

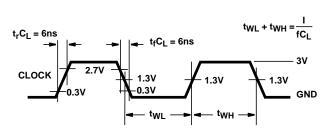
5. $P_D = V_{CC}^2 (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 2. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 3. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

зv

GND

3V

GND

3V

GND

GND

t_{TLH}

90%

1.3V

10%

1.3V

t_{H(L)}

tSU(L)

90%

1.3V

 C_L

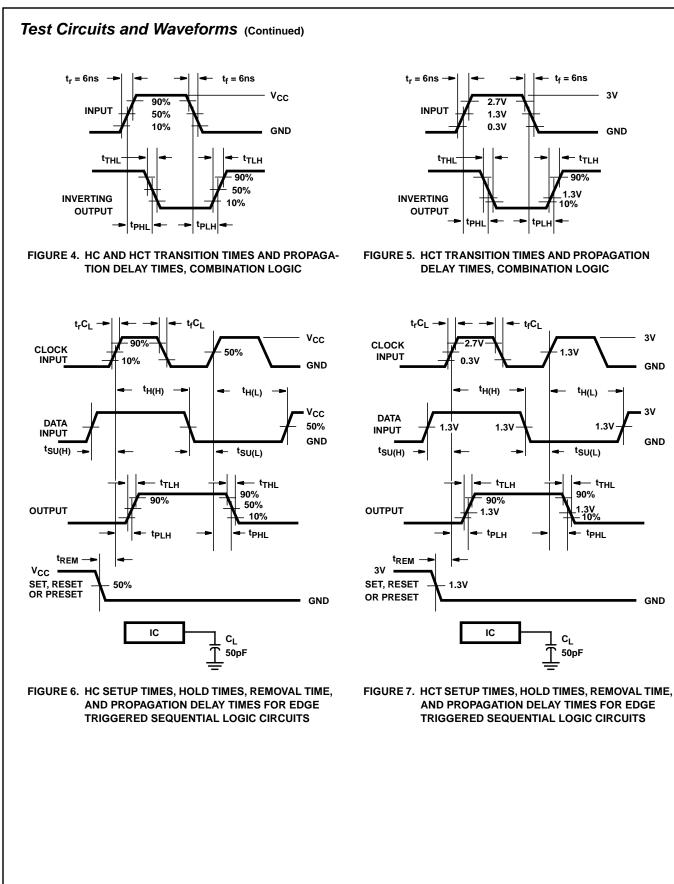
50pF

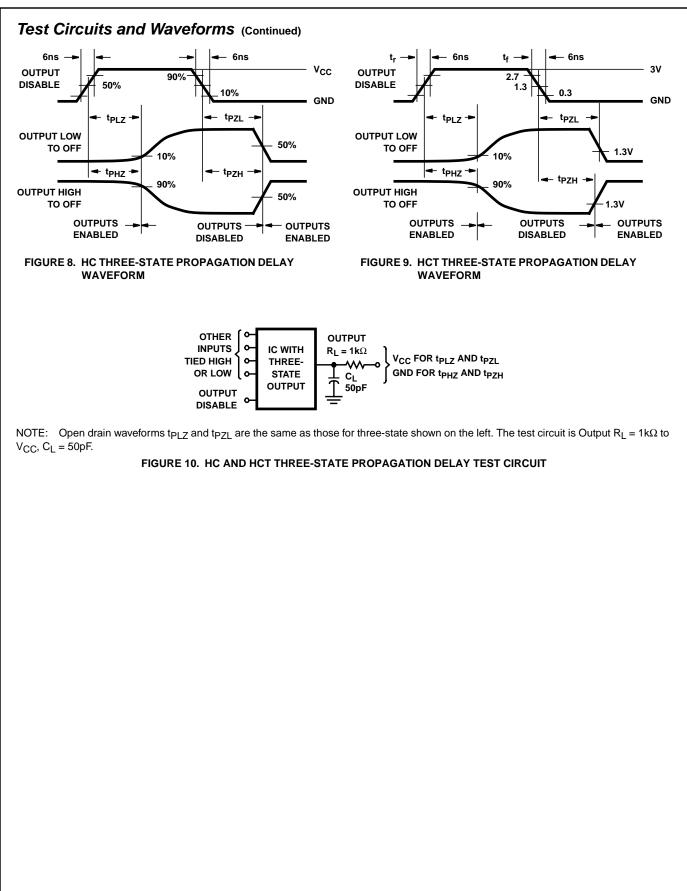
T

tPHL

1.3\

– t_{THL}





PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD54HC354F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC354E	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC354EE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT354E	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT354EE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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